## SPICE Device Model Si3430DV



Vishay Siliconix

## N-Channel 100 V (D-S) MOSFET

### DESCRIPTION

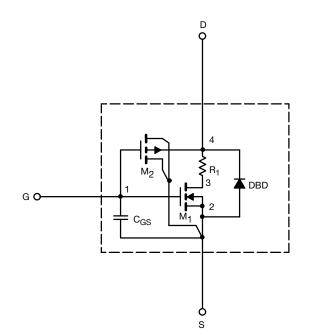
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	-	TYPICAL	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	-	3	V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	-	34	А
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.4 \text{ A}$	-	0.146	Ω
		$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 2.3 \text{ A}$	-	0.154	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 2.4 \text{ A}$	-	8.1	S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{S} = 1.7 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.72	V
Dynamic <sup>b</sup>					
Total Gate Charge <sup>b</sup>	Qg	$V_{DS}$ = 50 V, $V_{GS}$ = 10 V, $I_{D}$ = 2.4 A	-	6.06	nC
Gate-Source Charge <sup>b</sup>	Q <sub>gs</sub>		-	1.5	
Gate-Drain Charge <sup>b</sup>	Q <sub>gd</sub>		-	1.4	
Turn-On Delay Time	t <sub>d(on)</sub>	$\label{eq:V_DD} \begin{array}{l} V_{\text{DD}} = 50 \ \text{V}, \ R_{\text{L}} = 50 \ \Omega \\ I_{\text{D}} = 1 \ \text{A}, \ V_{\text{GEN}} = 10 \ \text{V}, \ R_{\text{g}} = 6 \ \Omega \end{array}$	-	8	ns
Rise Time <sup>b</sup>	tr		-	10	
Turn-Off Delay Time <sup>b</sup>	t <sub>d(off)</sub>		-	23	
Fall Time <sup>b</sup>	t <sub>f</sub>		-	30	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.7 A, dl/dt = 100 A/μs	-	52	ns

Notes

a. Pulse test; pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2~\%.$ 

b. Guaranteed by design, not subject to production testing.



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55°C

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VGS

4

5

4

6

8

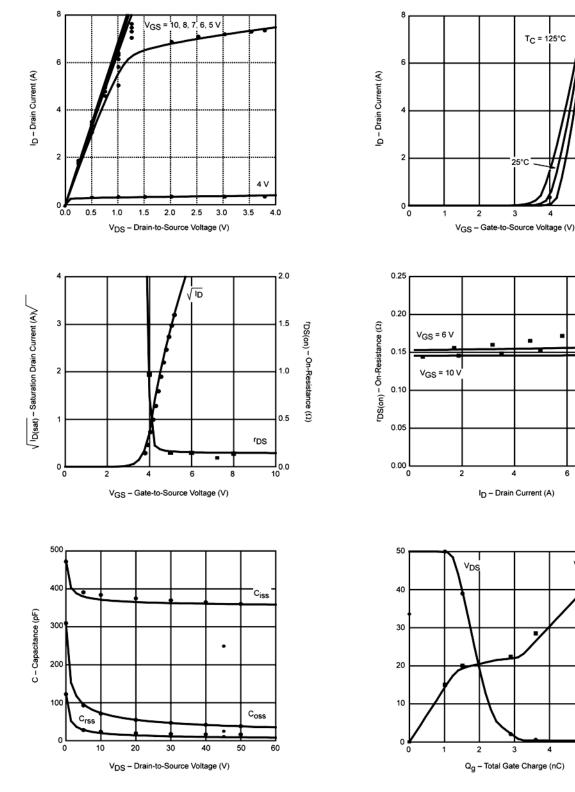
10

6

2

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### COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)



#### Note

• Dots and squares represent measured data.

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3



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